

OCT 05 2004

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October 5, 2004

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**To:** Examiner Ori Nadav  
**Firm:** Commissioner for Patents  
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Applicants : Chandra V. Mouli and Ceredig Roberts  
Serial No. : 09/648,044  
Filed : August 25, 2000  
Confirm No. : 6800  
Title : METHOD AND DEVICE TO REDUCE GATE-  
INDUCED DRAIN LEAKAGE (GIDL) CURRENT IN THIN GATE  
OXIDE MOSFETs  
Examiner : O. Nadav  
Art Unit : 2811

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Response Under 37 CFR 1.116  
Expedited Procedure  
Examining Group 2811

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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## Application of

Applicants : Chandra V. Mouli and Ceredig Roberts

Serial No. : 09/648,044

Filed : August 25, 2000

Confirm No. : 6800

Title : **METHOD AND DEVICE TO REDUCE GATE-INDUCED DRAIN  
LEAKAGE (GIDL) CURRENT IN THIN GATE OXIDE MOSFETs**

Docket No. : MIO 0054 PA/40509.90

Examiner : O. Nadav

Art Unit : 2811


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Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

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Office ((703) 872-9306) on October 5, 2004.

  
William A. Jviden, Esq. 42,695  
Reg. No.

Sir,

**AMENDMENT AFTER FINAL**

This paper is being filed in response to the Office Action mailed August 5, 2004, and made final. Reconsideration of the present application is respectfully requested in light of the amendments and remarks below, which include, in order of appearance, beginning on separate sheets:

- Amendments to the Claims; and
- Remarks.

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